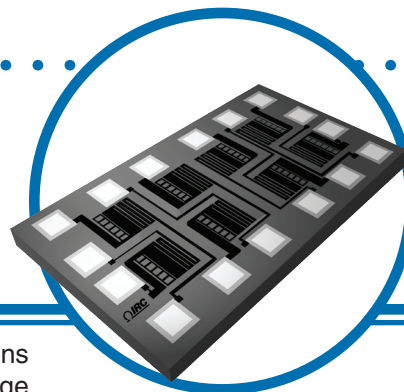


Wire Bondable Resistor Network Arrays

Chip Network Array Series

- Absolute tolerances to $\pm 0.1\%$
- Tight TCR tracking to $\pm 5\text{ppm}/^\circ\text{C}$
- Ratio match tolerances to $\pm 0.05\%$
- Ultra-stable tantalum nitride resistors



IRC's TaNSil® network array resistors are ideally suited for applications that demand a small footprint. The small wire bondable chip package provides higher component density, lower resistor cost and high reliability.

The tantalum nitride film system on silicon provides precision tolerance, exceptional TCR tracking and low cost. Excellent performance in harsh, humid environments is a trademark of IRC's self-passivating TaNSil® resistor film.

For applications requiring high performance resistor networks in a low cost, wire bondable package, specify IRC network array die.

Electrical Data

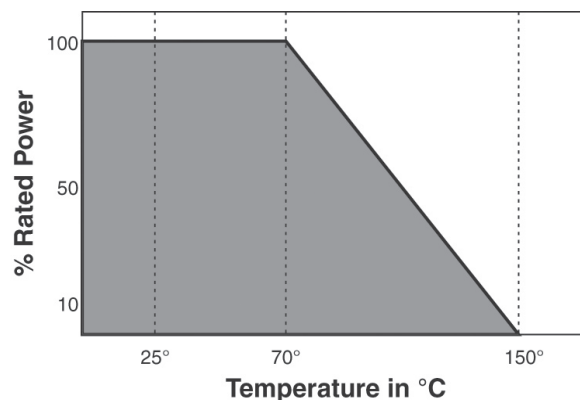
	Isolated	Bussed
Resistance Range	10 Ω to 2.5M Ω	10 Ω to 1.25M Ω
Absolute Tolerance	to $\pm 0.1\%$	
Ratio Tolerance to R1	to $\pm 0.05\%$	to $\pm 0.1\%$
Absolute TCR	to $\pm 25\text{ppm}/^\circ\text{C}$	
Tracking TCR	to $\pm 5\text{ppm}/^\circ\text{C}$	
Element Power Rating	100mW @ 70 $^\circ\text{C}$	50mW @ 70 $^\circ\text{C}$
Package Power Rating	8-Pad 400mW @ 70 $^\circ\text{C}$ 16-Pad 800mW @ 70 $^\circ\text{C}$ 24-Pad 1.0W @ 70 $^\circ\text{C}$	
Rated Operating Voltage (not to exceed $\sqrt{P \times R}$)	100V	
Operating Temperature	-55 $^\circ\text{C}$ to +150 $^\circ\text{C}$	
Noise	<-30dB	
Substrate Material	Oxidized Silicon (10K $\text{\AA}$ SiO ₂ minimum)	
Substrate Thickness	0.016" ± 0.001 (0.406mm ± 0.01)	
Bond Pad Metallization	Aluminum	10K $\text{\AA}$ minimum
	Gold	15K $\text{\AA}$ minimum
Backside	Silicon (gold available)	
Passivation	Silicon Dioxide or Silicon Nitride	

TCR/Inspection Code Table

Absolute TCR	Commercial Code	MIL Inspection Code*
$\pm 300\text{ppm}/^\circ\text{C}$	00	04
$\pm 100\text{ppm}/^\circ\text{C}$	01	05
$\pm 50\text{ppm}/^\circ\text{C}$	02	06
$\pm 25\text{ppm}/^\circ\text{C}$	03	07

*Notes: Product supplied to Class H of MIL-PRF 38534 include 100% visual inspection

Power Derating Data



General Note

IRC reserves the right to make changes in product specification without notice or liability. All information is subject to IRC's own data and is considered accurate at time of going to print.

Wire Bondable Resistor Network Arrays



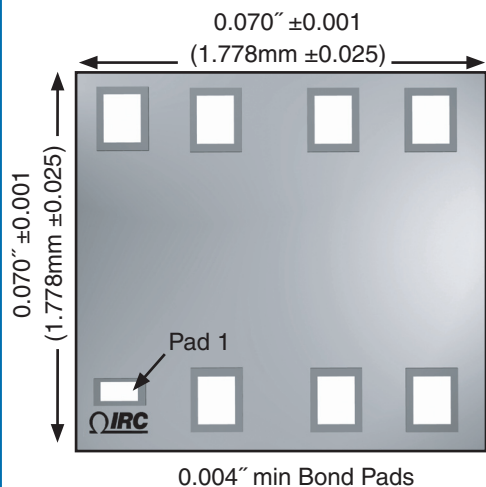
Manufacturing Capabilities Data

Absolute TCR ($\pm$ ppm/ $^{\circ}$ C)	Isolated schematic A				Bussed schematic B			
	Ohmic range (Ω)	Available tolerances	Available ratio tolerances	Best TCR tracking ($\pm$ ppm/ $^{\circ}$ C)	Ohmic range (Ω)	Available tolerances	Available ratio tolerances	Best TCR tracking ($\pm$ ppm/ $^{\circ}$ C)
300	10 - 25	F G J	F G	50	10 - 25	F G J	F G	200
	26 - 50	D F G J	C D F	10	26 - 50	F G J	D F G	100
	51 - 200	C D F G J	C D F G	5	51 - 100	D F G J	C D F G	50
	201 - 2.5M	B C D F G J	A B C D F G	5	101 - 200	D F G J	B C D F G	25
					201 - 500	B C D F G J	B C D F G	20
					501 - 1.25M	B C D F G J	A B C D F G	5
100	26 - 50	D F G J	C D F G	10	26 - 50	F G J	D F G	100
	51 - 200	C D F G J	C D F G	5	51 - 100	D F G J	C D F G	50
	201 - 2.5M	B C D F G J	A B F G	5	101 - 200	D F G J	B C D F G	25
					201 - 500	B C D F G J	B C D F G	20
					501 - 350K	B C D F G J	A B C D F G	5
50	26 - 50	D F G J	C D F G	10	51 - 100	D F G J	C D F G	50
	51 - 200	C D F G J	C D F G	5	101 - 200	D F G J	B C D F G	25
	201 - 2.5M	B C D F G J	A B F G	5	201 - 500	B C D F G J	B C D F G	20
					501 - 1.25M	B C D F G J	A B C D F G	5
25	51 - 200	C D F G J	C D F G	5	201 - 500	B C D F G J	B C D F G	20
	201 - 2.5M	B C D F G J	A B F G	5	501 - 1.25M	B C D F G J	A B C D F G	5

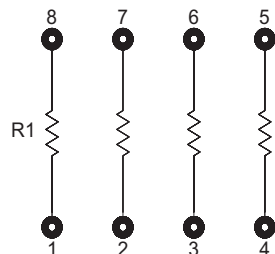
Wire Bondable Resistor Network Arrays

Physical Data

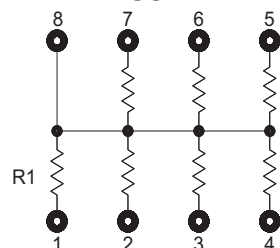
DSS4X



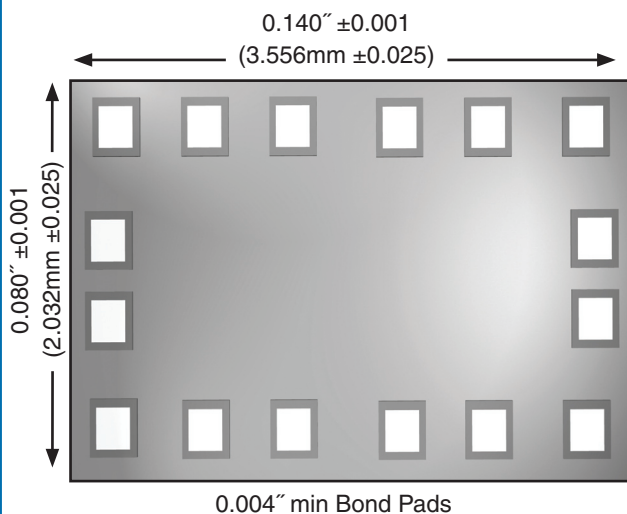
DSS4A



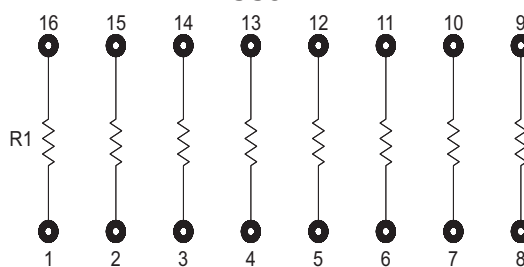
DSS4B



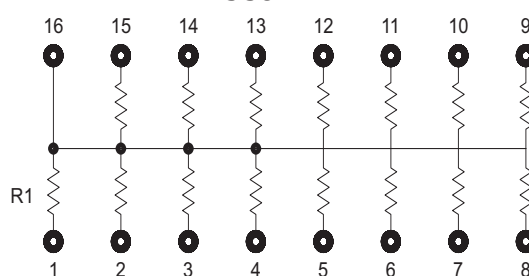
DSS8X



DSS8A



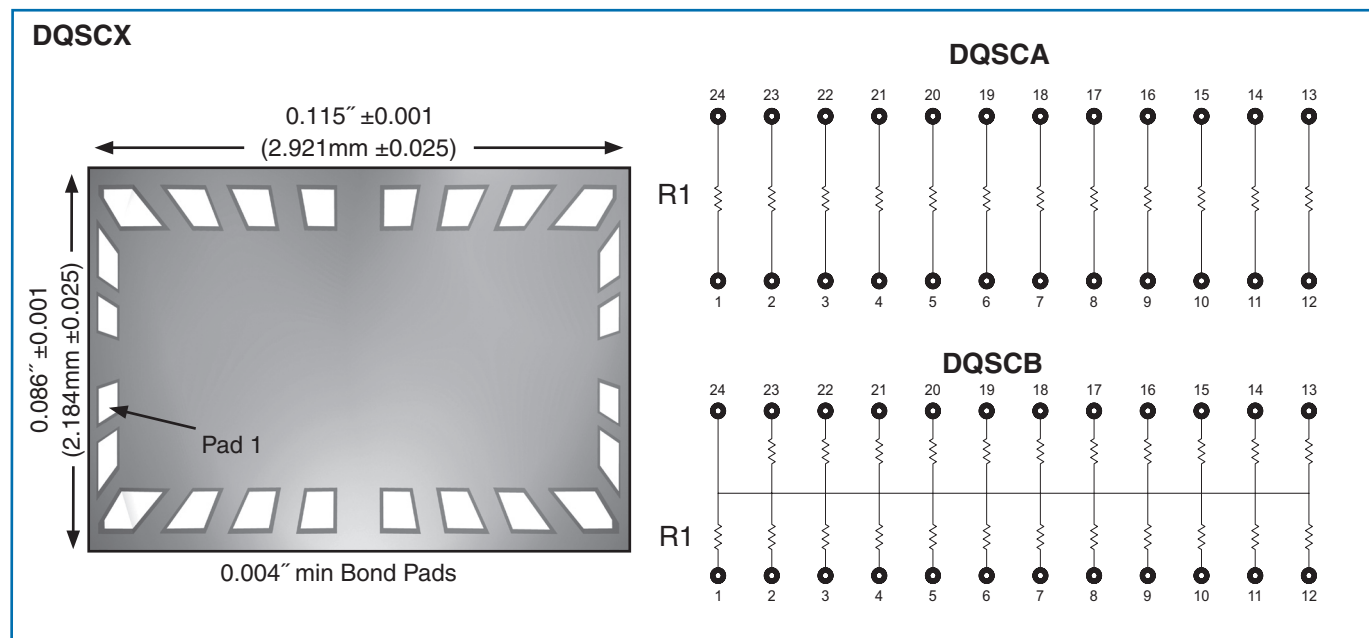
DSS8B



Wire Bondable Resistor Network Arrays



Physical Data



Environmental Data

Test	Method	Max ΔR	Typical ΔR
Thermal Shock	MIL-STD-202 Method 107 Test condition F	±0.1%	±0.02%
High Temperature Exposure	MIL-STD-883 Method 1008 150°C, 1000 hours	±0.1%	±0.05%
Low Temperature Storage	-55°C, 1000 hours	±0.03%	±0.01%
Life	MIL-STD-202 Method 108 70°C, 1000 hours	±0.5%	±0.01%
Life at Elevated Temperature	MIL-STD-202 Method 108 125°C, 1000 hours	±0.5%	±0.05%

Ordering Data

Prefix	WBD	DSS8	B	01	1002	F	B
Style	DSS4 = 8-pad Network DSS8 = 6-pad Network DQSC = 24-pad Network						
Schematic and Termination	A = Isolated; B = Bussed						
TCR/Inspection Code	Reference TCR/Inspection Code Table						
Resistance Code	4-Digit Resistance Code Ex: 1002 = 10K Ω , 50R1 = 50.1 Ω						
Absolute Tolerance Code	J = ±5%; G = ±2%; F = ±1%; D = ±0.5%; C = ±0.25%; B = ±0.1%						
Ratio Tolerance Code (optional)	G = ±2%; F = ±1%; D = ±0.5%; C = ±0.25%; B = ±0.1%; A = 0.05%						
Packaging	Standard packaging is 2" x 2" chip tray. For additional information or to discuss your specific requirements, please contact our Applications Team using the contact details below.						